

BT138X-800 4Q Triac Rev.03 - 30 January 2023

Product data sheet

1. General description

Planar passivated four quadrant triac in a TO220F "full pack" plastic package intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

2. Features and benefits

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- High blocking voltage capability
- High noise immunity •
- Isolated package
- · Less sensitive gate for improved noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants

3. Applications

- General purpose motor control • •
 - General purpose switching

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	800	V
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	95	A
T _j	junction temperature		-	-	125	°C
$I_{T(RMS)}$	RMS on-state current	full sine wave; T _h ≤ 56 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	12	A
Static ch	aracteristics					
I _{GT} g	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-	5	35	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	8	35	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	10	35	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _i = 25 °C; <u>Fig. 7</u>	-	22	70	mA

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Dynamic characteristics							
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		100	250	-	V/µs

5. Pinning information

Table 2. F	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	
2	T2	main terminal 2		
3	G	gate		T2-T1
mb	n.c.	mounting base; isolated		sym051

6. Ordering information

Table	2	Ordening	information.
lable	J .	Ordering	information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BT138X-800	TO220F	BT138X-800,127	Tube	50	SOT186A	14-Nov-2013

7. Marking

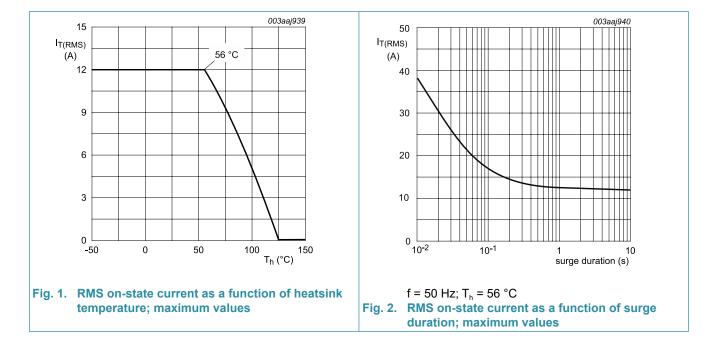
Table 4. Marking codes						
Type number	Marking codes	Marking codes				
	Assembly factory: d	Assembly factory: A				
BT138X-800	BT138X 800	BT138X 800				
	PJdxxxx xx	PJAxxxx xx				

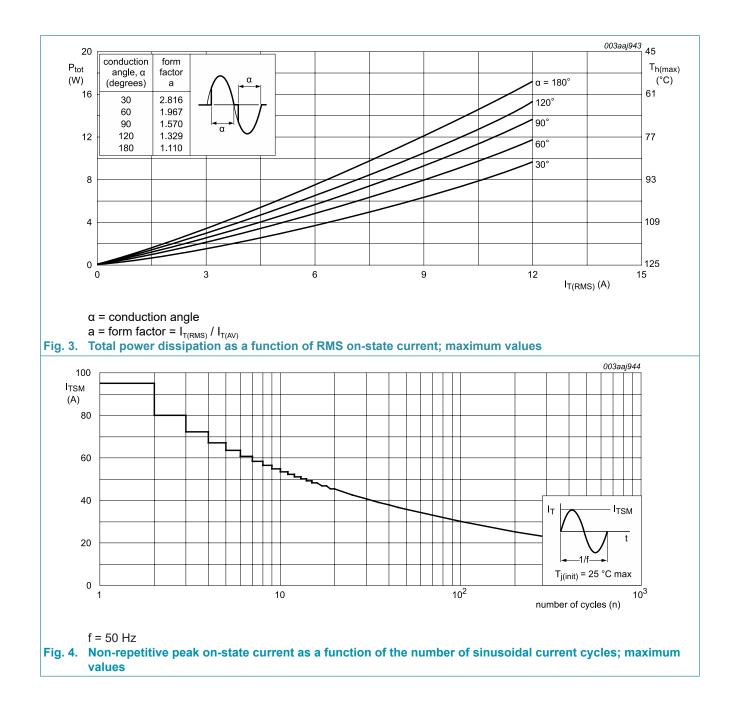
8. Limiting values

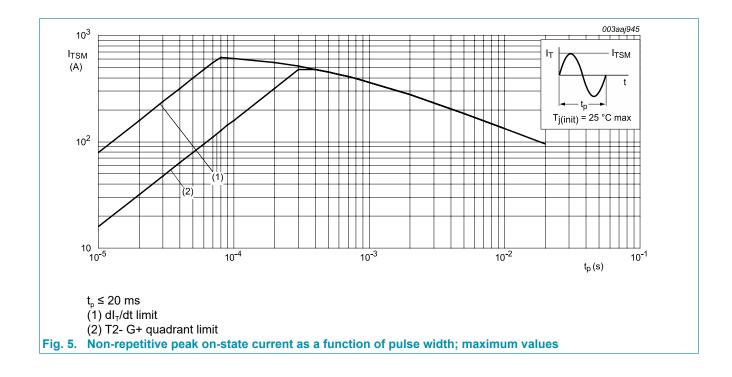
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 56 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	12	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	95	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	105	А
l²t	l ² t for fusing	t _p = 10 ms; sine-wave pulse	-	45	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 70 mA; T2+ G+	-	50	A/µs
		I _G = 70 mA; T2+ G-	-	50	A/µs
		I _G = 70 mA; T2- G-	-	50	A/µs
		I _G = 140 mA; T2- G+	-	10	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

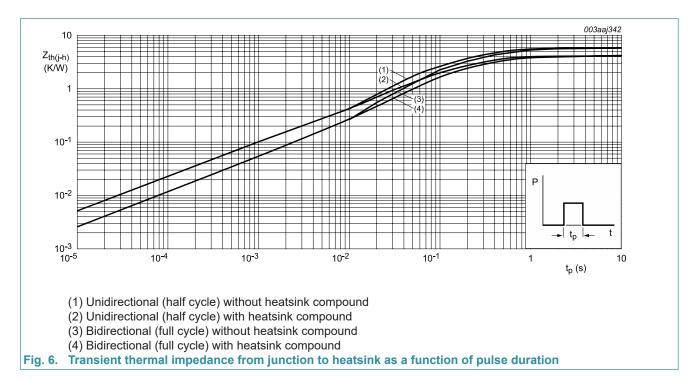






9. Thermal characteristics

Table 6. Th	ermal characteristics		 			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
from	thermal resistance from junction to	full or half cycle; with heatsink compound <u>; Fig. 6</u>	-	-	4	K/W
	heatsink	full or half cycle; without heatsink compound; Fig. 6	-	-	5.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W

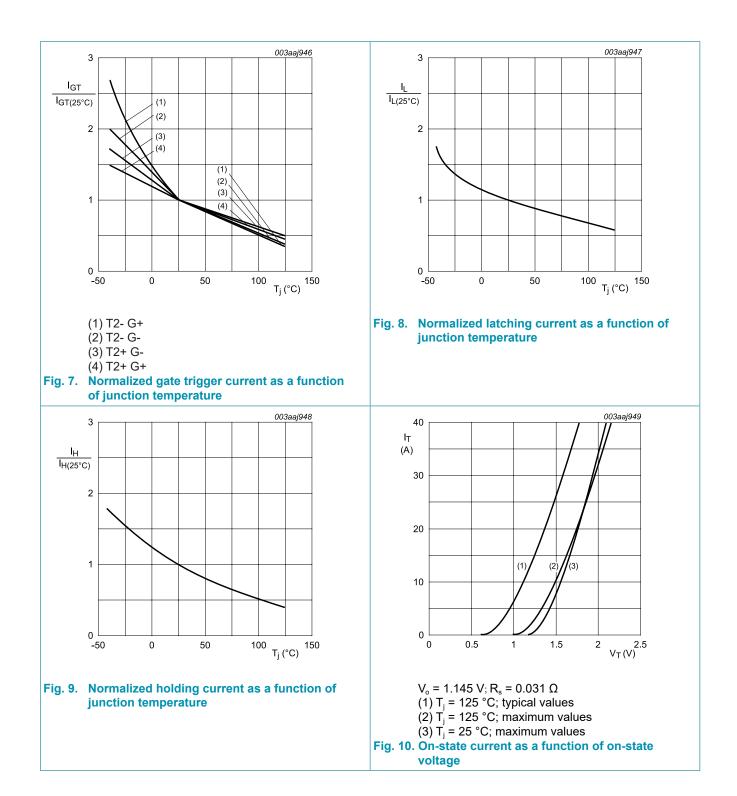


10. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C	-	-	2500	V
C _{isol}	isolation capacitance	from main terminal 2 to external heatsink; f = 1 MHz; T _h = 25 °C	-	10	-	pF

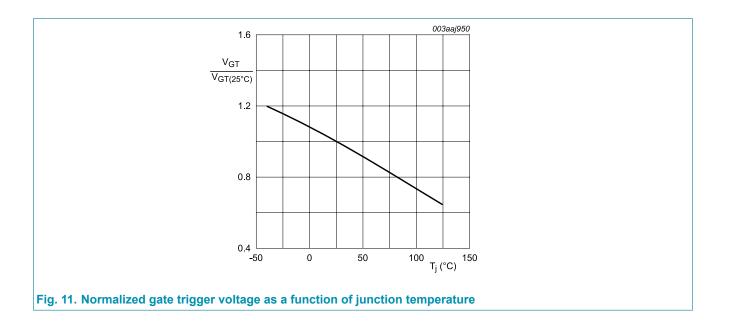
11. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-	5	35	mA
		V_{D} = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	8	35	mA
		V_{D} = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	10	35	mA
		V_{D} = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>	-	22	70	mA
l	latching current	V_{D} = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; Fig. 8	-	7	40	mA
		V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	20	60	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	8	40	mA
		V_{D} = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 8</u>	-	10	60	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	6	30	mA
V _T	on-state voltage	I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.65	V
V _{gt}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>	-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C	0.25	0.4	-	V
I _D	off-state current	V _D = 800 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	1				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	100	250	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 16 A; V_D = 800 V; I_G = 0.1 A; d_{IG}/dt = 5 A/µs	-	2	-	μs
	1	1	1			



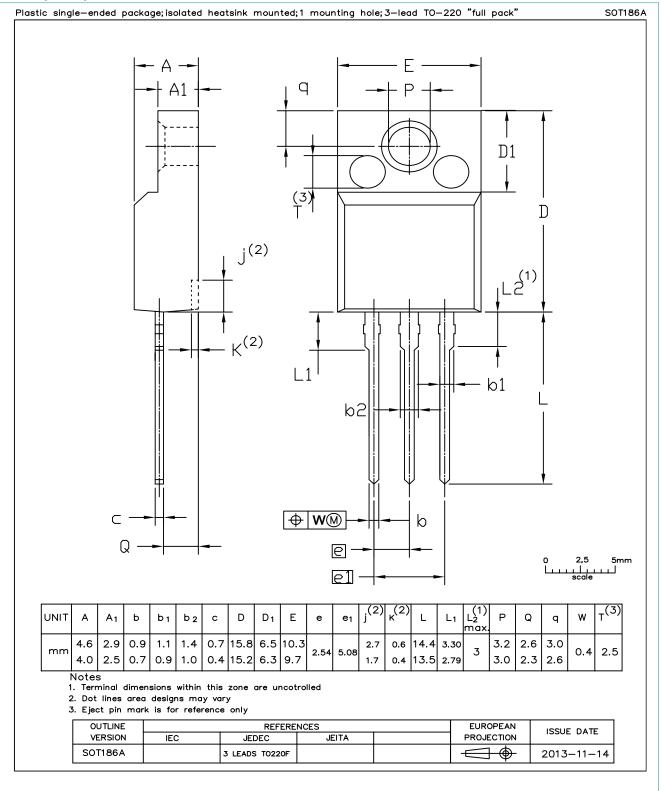
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12. Package outline

Assembly factory: d & A



BT138X-800 Product data sheet

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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